

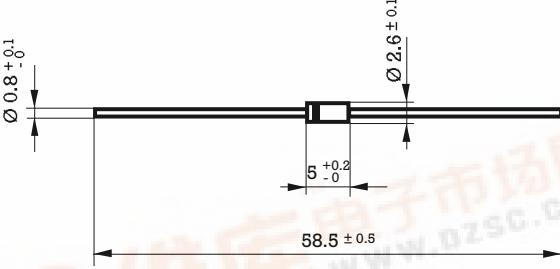


查询BYV26C供应商

捷多邦，专业PCB打样工厂，24小时加急出货

BYV26A.....BYV26E

1 Amp. Very Fast Soft Recovery Glass Passivated Avalanche Diode

Dimensions in mm.	DO-41 (Plastic)	Voltage 200 to 1000 V.	Current 1 A at 55 °C.
			
Mounting instructions			<ul style="list-style-type: none">• Glass Passivated Junction• High current capability• The plastic material carries U/L recognition 94 V-0• Terminals: Axial Leads• Polarity: Color band denotes cathode

Maximum Ratings, according to IEC publication No. 134

	BYV26A	BYV26B	BYV26C	BYV26D	BYV26E
V_{RRM}	Peak Recurrent reverse voltage (V)	200	400	600	800
V_{RMS}	Maximum RMS voltage	140	280	420	560
V_{DC}	Maximum DC blocking voltage	200	400	600	800
$I_{F(AV)}$	Forward current at Tamb = 55 °C	1 A			
I_{FRM}	Recurrent peak forward current	10 A			
I_{FSM}	10 ms. peak forward surge current	30 A			
t_{rr}	Max. reverse recovery time from $I_F = 0.5 \text{ A}$; $I_R = 1 \text{ A}$; $I_{RR} = 0.25 \text{ A}$	30 ns		75 ns	
V_{BR}	Avalanche breakdown voltage at 100 μA (V)	>300	>500	>700	>900
T_j	Operating temperature range	−65 to +175 °C			
T_{stg}	Storage temperature range	−65 to +175 °C			
E_{RSM}	Maximum non repetitive peak reverse avalanche energy. $I_R = 0.5 \text{ A}$; $T_j = 25 \text{ °C}$	20 mJ			

Electrical Characteristics at Tamb = 25 °C

V_F	Max. forward voltage drop at $I_F = 1 \text{ A}$	at 25 °C	2.5 V
		at 175 °C	1.3 V
I_R	Max. reverse current at V_{RRM}	at 25 °C	5 μA
R_{Th}	Max. thermal resistance ($l = 10 \text{ mm.}$)	at 165 °C	150 μA
			50 °C/W

Rating And Characteristic Curves

